

Product data sheet

## 1. General description

Silicon Carbide Schottky diode in a SOD59A (TO-220AC) plastic package, designed for high frequency switched-mode power supplies.

### 2. Features and benefits

- Highly stable switching performance
- High forward surge capability I<sub>FSM</sub>
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

## 3. Applications

- Power factor correction
- Telecom/Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED/OLED TV
- Motor Drives

### 4. Quick reference data

Table 1. Qui	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		-	-	650	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5; T <sub>mb</sub> ≤ 136 °C; square-wave pulse; <u>Fig. 1</u> ; <u>Fig. 2</u>	-	-	4	A
Tj	junction temperature		-	-	175	°C
Static charact	eristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 4</u>	-	1.5	1.7	V





### **NXP Semiconductors**

# **NXPSC04650**

#### Silicon Carbide Diode

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Dynamic chara	acteristics					
Qr	recovered charge	$I_F = 4 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \underline{Fig. 5}$	-	7	-	nC

# 5. Pinning information

Symbol K A	Description cathode	Simplified outline	Graphic symbol
	cathode	mb	
А			K A
	anode	205	001aaa020
mb	mounting base; connected to cathode	TO-220AC (SOD59A)	
1	пb	_	cathode

## 6. Ordering information

Table 3.	Ordering information	

Type number	Package					
	Name	Description	Version			
NXPSC04650	TO-220AC	Plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59A			

## 7. Marking

Table 4. Marking codes	
Type number	Marking code
NXPSC04650	NXPSC04650

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### 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		-	650	V
V <sub>RWM</sub>	crest working reverse voltage		-	650	V
V <sub>R</sub>	reverse voltage	DC	-	650	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5; T <sub>mb</sub> ≤ 136 °C; square-wave pulse; <u>Fig. 1</u> ; Fig. 2	-	4	A
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5; t <sub>p</sub> = 25 µs; T <sub>mb</sub> ≤ 136 °C; square-wave pulse	-	8	A
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	24	A
		$t_p$ = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse	-	235	A
T <sub>stg</sub>	storage temperature		-55	175	°C
Tj	junction temperature		-	175	°C

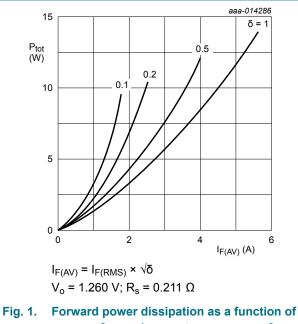


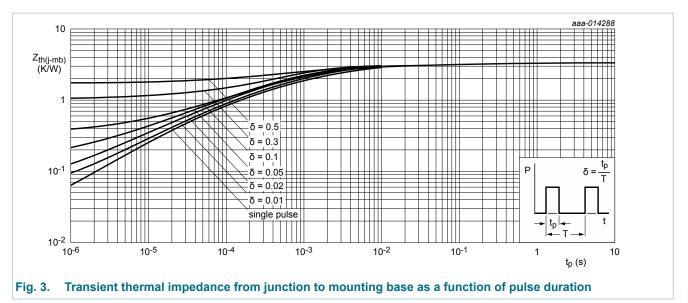


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

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### 9. Thermal characteristics

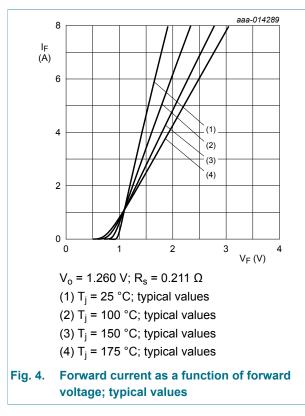
Table 6. T	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 3	-	-	3.3	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	-	60	-	K/W

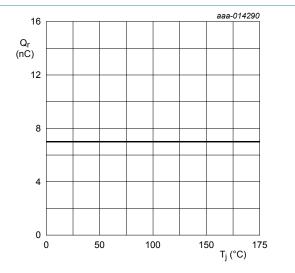


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### **10. Characteristics**

Table 7. C	haracteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static chara	octeristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 4</u>	-	1.5	1.7	V
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 150 °C; <u>Fig. 4</u>	-	1.8	2.1	V
I <sub>R</sub> reverse current		V <sub>R</sub> = 650 V; T <sub>j</sub> = 25 °C	-	-	170	μA
		V <sub>R</sub> = 650 V; T <sub>j</sub> = 150 °C	-	-	550	μA
Dynamic ch	aracteristics					
Qr	recovered charge	$I_{F} = 4 \text{ A; } dI_{F}/dt = 500 \text{ A}/\mu\text{s; } V_{R} = 400 \text{ V;}$ $T_{j} = 25 \text{ °C; } \frac{\text{Fig. 5}}{5}$	-	7	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C	-	130	-	pF
		f = 1 MHz; V <sub>R</sub> = 300 V; T <sub>j</sub> = 25 °C	-	16	-	pF
		f = 1 MHz; $V_R$ = 600 V; $T_j$ = 25 °C	-	13	-	pF



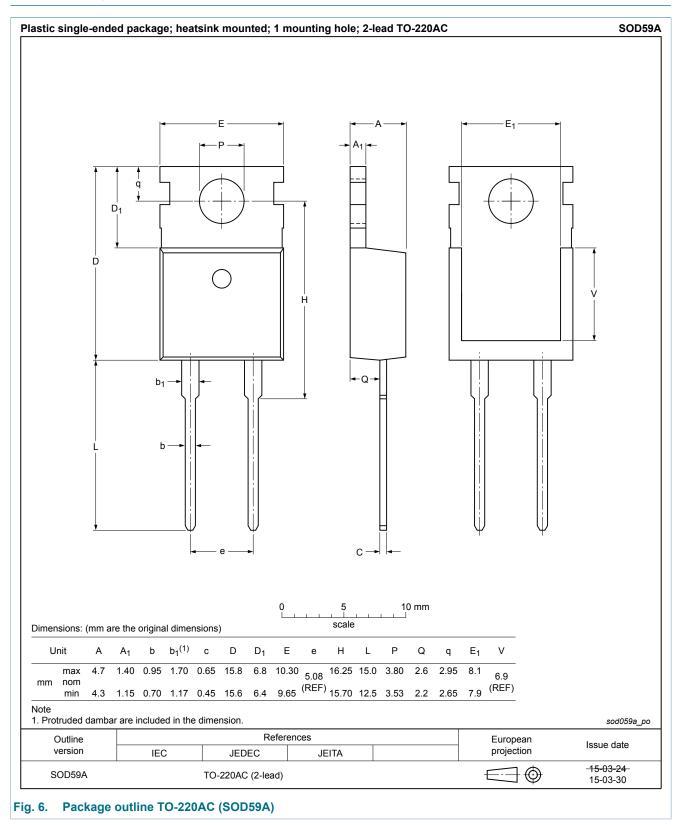






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### 11. Package outline



NXPSC04650

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#### 12. Legal information

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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